

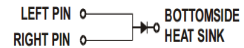
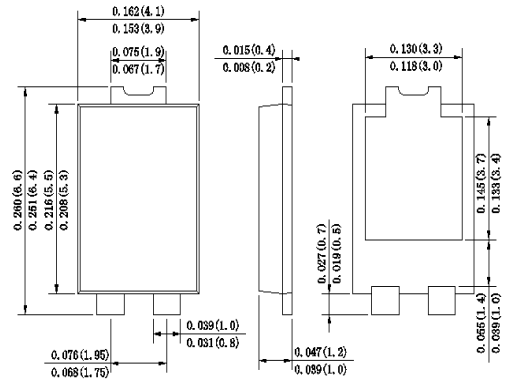


## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

### Features

- ◆ Trench MOS Schottky barrier diodes
- ◆ Low forward voltage drop
- ◆ low profile - typical body height 1.1 mm
- ◆ Moisture sensitivity: level 1, per J-STD-020
- ◆ High temperature soldering guaranteed:  
260 °C/10 seconds - RoHS Compliant
- ◆ Halogen-free according to IEC 61249-2-21 definition

TO-277



Dimensions in inches and (millimeters)

### Mechanical Data

**Case :** JEDEC TO-277 Molded plastic body  
Case Material: Molding compound meets UL 94V-0 flammability rating

**Terminals :**Plated Leads Solderable per MIL-STD-202,Method 208

**Polarity :** Polarity symbol marking on body

**Mounting Position :** Any

**Weight :** 0.003 ounce, 0.092 grams

### Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOL	ST2045		UNIT
		MDD	ST2045	
Marking Code				
Maximum repetitive peak reverse voltage	$V_{RRM}$	45		V
Maximum DC blocking voltage	$V_{DC}$			
RMS Reverse voltage	$V_{RMS}$	32		V
Average Rectified Output Current	$I_{(O)}$	20		A
Non-Repetitive Peak Forward Surge 8.3ms Single Half Sine-Wave Superimposed on rated load(JEDEC Method)	$I_{FSM}$	400		A

Electrical Characteristics  $T_a=25^\circ\text{C}$  unless otherwise noted

Parameter	Test Conditions	Symbol	Value		Unit
			Typ	Max	
Forward Voltage Drop at 20A	$T_A=25^\circ\text{C}$	$V_F$	0.47	0.50	V
	$T_A=125^\circ\text{C}$		0.42	0.45	
Peak reverse current at rated DC blocking voltage	$T_A=25^\circ\text{C}$	$I_R$	35	60	uA
	$T_A=125^\circ\text{C}$		40	70	
Operating junction storage temperature range		$T_J$	-55 to +150		°C
Storage temperature range		$T_{STG}$	-55 to +150		°C
Typical thermal resistance Junction to Ambient		$R_{\theta JC}$	1		°C/W

**Note:** 1. The typical data above is for reference only.

DN:T20305A0



## Ratings And Characteristic Curves

FIG.1: Forward Output Current Derating Curve

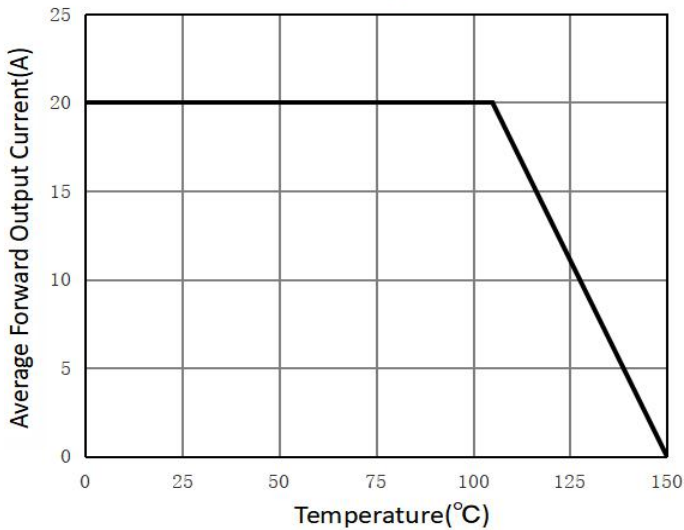


FIG.2: Maximum Non-Repetitive Peak Forward Surge Current

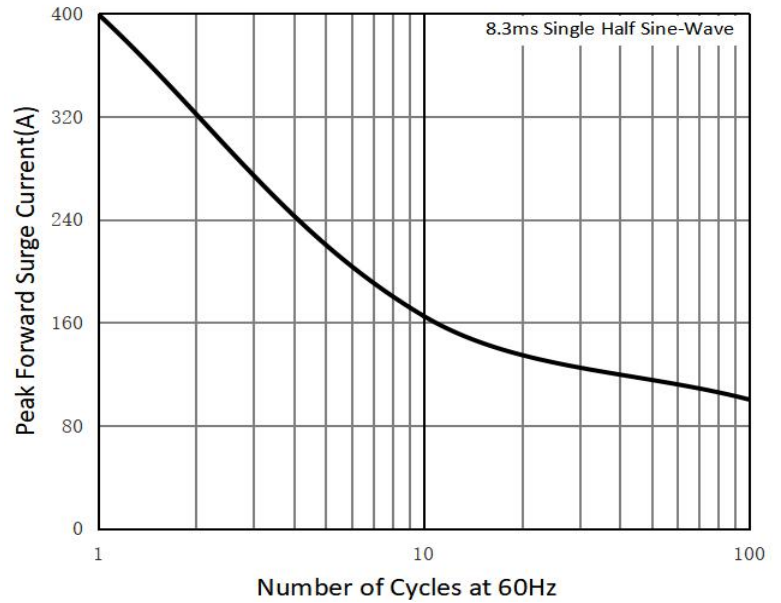


FIG.3: Typical Instantaneous Forward Characteristics

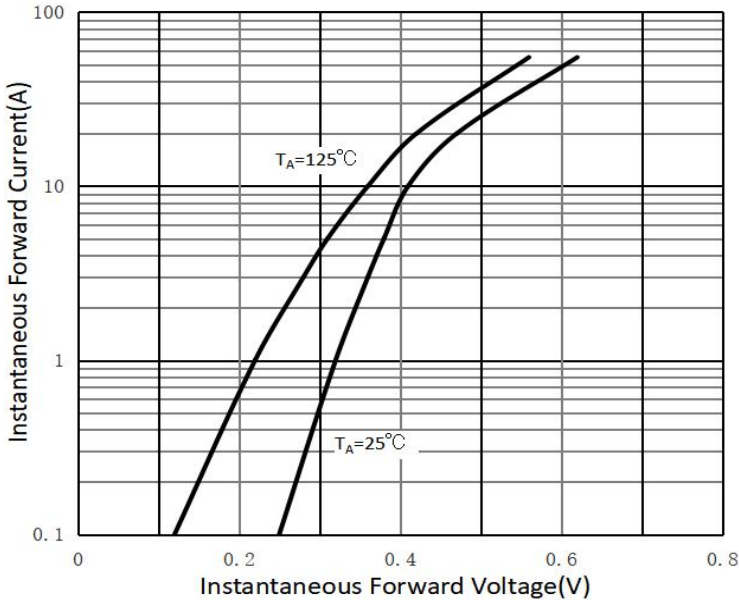
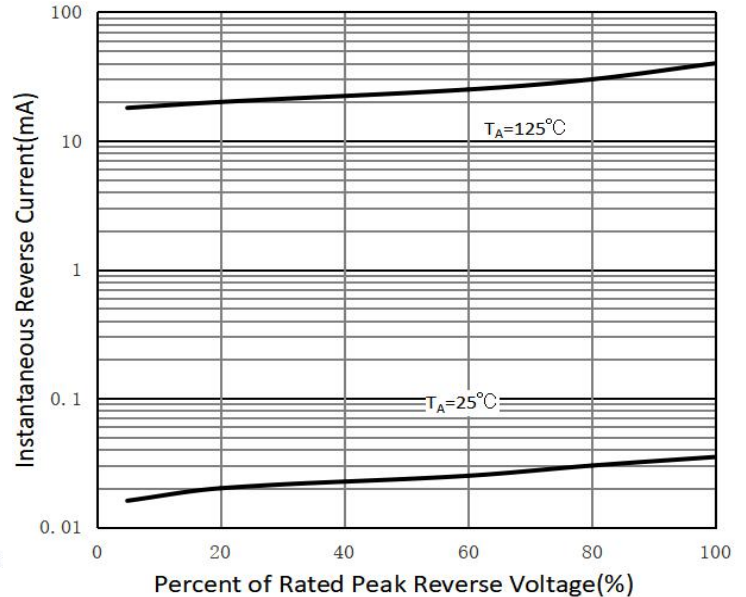
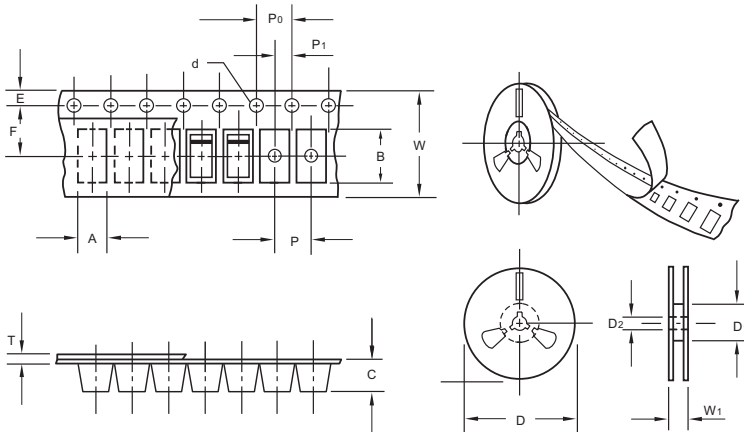


FIG.4: Typical Reverse Characteristics



The curve above is for reference only.

## Packing information



unit:mm

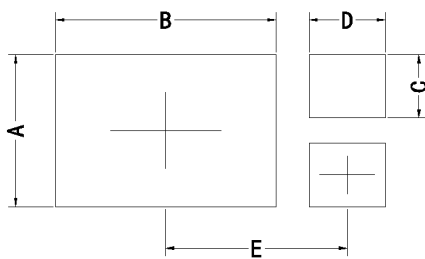
Item	Symbol	Tolerance	TO-277
Carrier width	A	0.1	4.45
Carrier length	B	0.1	7.0
Carrier depth	C	0.1	1.60
Sprocket hole	d	0.05	1.55
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D <sub>1</sub>	min	50.0
Feed hole diameter	D <sub>2</sub>	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	7.50
Punch hole pitch	P	0.1	8.00
Sprocket hole pitch	P <sub>0</sub>	0.1	4.00
Embossment center	P <sub>1</sub>	0.1	2.00
Overall tape thickness	T	0.1	0.25
Tape width	W	0.3	12.00
Reel width	W <sub>1</sub>	1.0	12.30

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

## Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
TO-277	13"	5,000	4.0	10,000	210*208*203	330	430*430*235	80,000	13.0

## Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
A	3.60	0.142
B	5.35	0.211
C	1.50	0.059
D	1.85	0.073
E	4.30	0.169

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